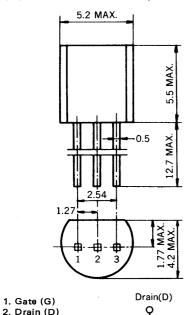
SEC ARESER OF DEVICE

DATA SHEET

MOS FIELD EFFECT TRANSISTOR **2SK1482**

N-CHANNEL MOS FET FOR SWITCHING

PACKAGE DIMENSIONS (Unit: mm)



(Diode in the figure is the parastic diode.)

Source(S)

Gate(G)

The 2SK1482 is an N-channel vertical type MOS FET switching device which can be directly driven from an IC operating with a 5 V single power supply. The device featuring low ON-state resistance is of the voltage drive type and thus is ideal for driving actuators such as motors, solenoids, and relays.

FEATURES

Low ON-state resistance

 $R_{DS(on)}$ = 0.8 Ω MAX. at V_{GS} = 4 V, I_D = 0.5 A $R_{DS(on)}$ = 0.4 Ω MAX. at V_{GS} = 10 V, I_D = 0.5 A

- Voltage drive at logic level (V_{GS} = 4 V) is possible.
- Bidirectional zener diode for protection is incorporated in between the gate and the source.
- Inductive loads can be driven without protective circuit thanks to the improved breakdown voltage between the drain and
- Can be used complementary with the 2SJ196

QUALITY GRADE

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS ($T_a = 25$ °C)

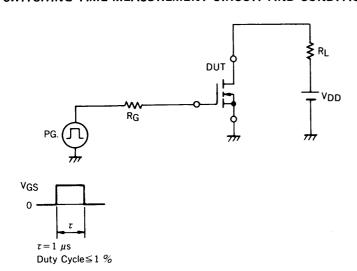
PARAMETER	SYMBOL	RATINGS	UNIT	TEST CONDITIONS	
Drain to Source Voltage	V _{DSS}	30	V	V _{GS} = 0	
Gate to Source Voltage	V _{GSS}	±20	V	V _{DS} = 0	
Drain Current (DC)	ID(DC)	±1.5	Α		
Drain Current (pulse)	^I D(pulse)	±3.0	А	PW ≤ 10 ms, Duty Cycle ≤ 50 %	
Total Power Dissipation	PT	750	mW		
Channel Temperature	T _{ch}	150	°C		
Storage Temperature	T _{stg}	-55 to +150	°C		

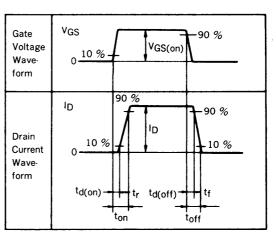
3. Source (S)

ELECTRICAL CHARACTERISTICS ($T_a = 25$ °C)

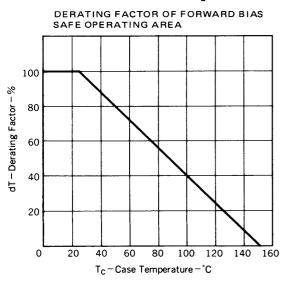
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain Cut-off Current	IDSS			10	μΑ	V _{DS} = 30 V, V _{GS} = 0
Gate Leakage Current	IGSS			±10	μΑ	V _{GS} = ±20 V, V _{DS} = 0
Gate Cut-off Voltage	V _{GS(off)}	1.3	1.8	2.5	V	V _{DS} = 10 V, I _D = 1 mA
Forward Transfer Admittance	lyfs l	0.4			s	V _{DS} = 10 V, I _D = 0.5 A
Drain to Source On-State Resistance	R _{DS(on)1}		0.4	8.0	Ω	V _{GS} = 4.0 V, I _D = 0.5 A
Drain to Source On-State Resistance	R _{DS(on)2}		0.15	0.4	Ω	V _{GS} = 10 V, I _D = 0.5 A
Input Capacitance	C _{iss}		230		pF	V _{DS} = 10 V, V _{GS} = 0, f = 1 MHz
Output Capacitance	Coss		170		pF	
Feedback Capacitance	C _{rss}		45		pF	
Turn-On Delay Time	^t d(on)		15		ns	$V_{GS(on)}$ = 10 V, R_G = 10 Ω VDD = 25 V, I_D = 0.5 A R_L = 50 Ω
Rise Time	t _r		50		ns	
Turn-Off Delay Time	^t d(off)		420		ns	
Fall Time	t _f		240		ns	

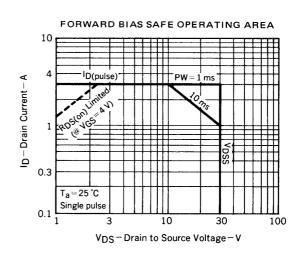
SWITCHING TIME MEASUREMENT CIRCUIT AND CONDITIONS



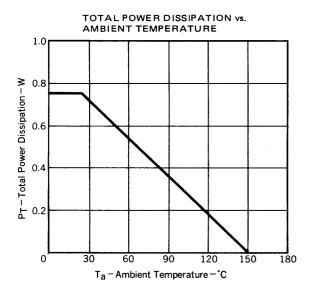


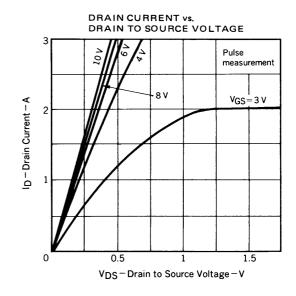
TYPICAL CHARACTERISTICS (T_a = 25 °C)

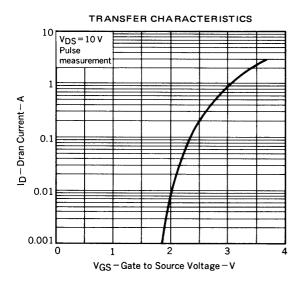


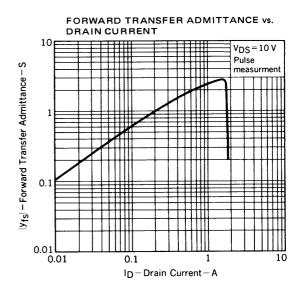


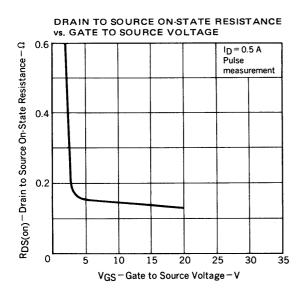


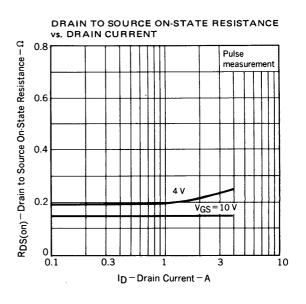


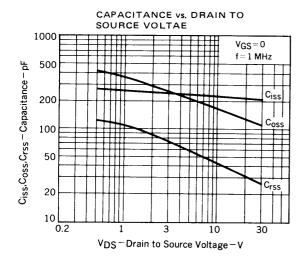


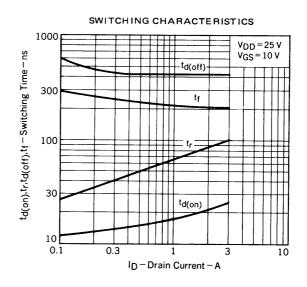


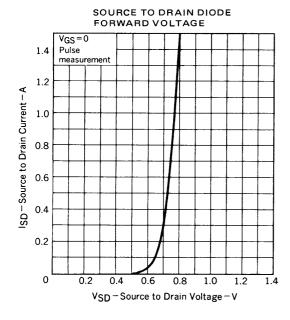












RECOMMENDED SOLDERING CONDITIONS

Solder this product under the following recommended conditions.

For soldering methods or soldering conditions other than those recommended in the table, please consult our NEC salespeople.

Insert type

Soldering method	Soldering conditions	Recommended condition code
Wave soldering	Solder bath temperature: 260 °C max. Soldering time: 10 sec max.	

(MEMO)

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The devices listed in this document are not suitable for use in the field where very high reliability is required including, but not limited to, aerospace equipment, submarine cables, unclear reactor control systems and life support systems. If customers intend to use NEC devices for above applications or those inted to use "Standard", or "Special" quality grade NEC devices for the applications not intended by NEC, please contact our sales people in advance.

Application examples recomended by NEC Corporation

Standard: Data processing and office equipment, Communication equipment (terminal, mobile). Test and

Measurement equipment, Audio and Video equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Communication equipment (trunk line), Train and

Traffic control devices, industrial robots, Burning control systems, antidisaster systems, anticrime

systems etc.